

4V Drive Pch + Pch MOSFET

QS8J5

Structure

Silicon P-channel MOSFET

Features

1) Low on-resistance.

- 2) High power package(TSMT8).
- 3) Low voltage drive(4V drive).

Application

Switching

Packaging specifications

| | Package | Taping |
|-------|------------------------------|--------|
| Туре | Code | TR |
| | Basic ordering unit (pieces) | 3000 |
| QS8J5 | | 0 |

• Absolute maximum ratings (Ta = 25°C)

| | Tailige (Ta Lo | 0) | | | |
|-----------------------|----------------|-------------------|-------------|-------------|--|
| Parameter | | Symbol | Limits | Unit | |
| Drain-source voltage | | V _{DSS} | -30 | V | |
| Gate-source voltage | | V _{GSS} | ±20 | V | |
| Drain current | Continuous | I _D | ±5 | А | |
| | | ا _{DP} 1 | ±20 | А | |
| Source current | Continuous | l _s | -1 | А | |
| (Body Diode) | Pulsed | ^{*1} ا | -20 | А | |
| Power dissipation | | P _D *2 | 1.5 | W / TOTAL | |
| | | · D - | 1.25 | W / ELEMENT | |
| Channel temperature | | Tch | 150 | °C | |
| Range of storage temp | erature | Tstg | -55 to +150 | °C | |
| | | | | | |

*1 Pw≤10μs, Duty cycle≤1%

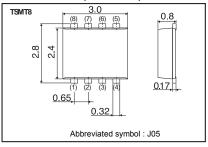
*2 Each terminal mounted on a ceramic board.

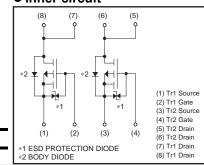
Thermal resistance

| Parameter | Symbol | Limits | Unit |
|--------------------|-------------|--------|-----------------|
| Channel to ambient | Rth (ch-a) | 83.3 | °C / W /TOTAL |
| | Rui (cii-a) | 100 | °C / W /ELEMENT |

* Each terminal mounted on a ceramic board.

• Dimensions (Unit : mm)





Inner circuit

• Electrical characteristics (Ta = 25°C)

<It is the same ratings for Tr1 and Tr2.>

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|---|-----------------------|------|------|------|------|---|
| Gate-source leakage | I _{GSS} | - | - | ±10 | μA | V _{GS} =±20V, V _{DS} =0V |
| Drain-source breakdown voltage | V _{(BR)DSS} | -30 | - | - | V | I _D =–1mA, V _{GS} =0V |
| Zero gate voltage drain current | I _{DSS} | - | - | -1 | μA | V _{DS} =-30V, V _{GS} =0V |
| Gate threshold voltage | V _{GS (th)} | -1.0 | - | -2.5 | V | V_{DS} =-10V, I_{D} =-1mA |
| | * | - | 28 | 39 | | I _D =–5A, V _{GS} =–10V |
| Static drain-source on-state resistance | R _{DS (on)} | - | 40 | 56 | mΩ | I _D =-2.5A, V _{GS} =-4.5V |
| | | - | 45 | 63 | | I _D =-2.5A, V _{GS} =-4V |
| Forward transfer admittance | ۱ Y _{fs} ľ* | 3 | - | - | S | I _D =–5A, V _{DS} =–10V |
| Input capacitance | C _{iss} | - | 1100 | - | pF | V _{DS} =-10V |
| Output capacitance | C _{oss} | - | 150 | - | pF | V _{GS} =0V |
| Reverse transfer capacitance | C _{rss} | - | 130 | - | pF | f=1MHz |
| Turn-on delay time | t _{d(on)} * | - | 9 | - | ns | I _D =–2.5A, V _{DD} ≒–15V |
| Rise time | t _r * | - | 40 | - | ns | V _{GS} =–10V |
| Turn-off delay time | t _{d(off)} * | - | 90 | - | ns | R _L ≒6Ω |
| Fall time | t _f * | - | 55 | - | ns | R_G =10 Ω |
| Total gate charge | Q _g * | - | 10.0 | - | nC | I _D =–5A, V _{DD} ≒−15V |
| Gate-source charge | Q _{gs} * | - | 3.6 | - | nC | V _{GS} =–5V |
| Gate-drain charge | Q _{gd} * | - | 3.0 | - | nC | R _L ≒3Ω, R _G =10Ω |

*Pulsed

•Body diode characteristics (Source-Drain) (Ta = 25°C)

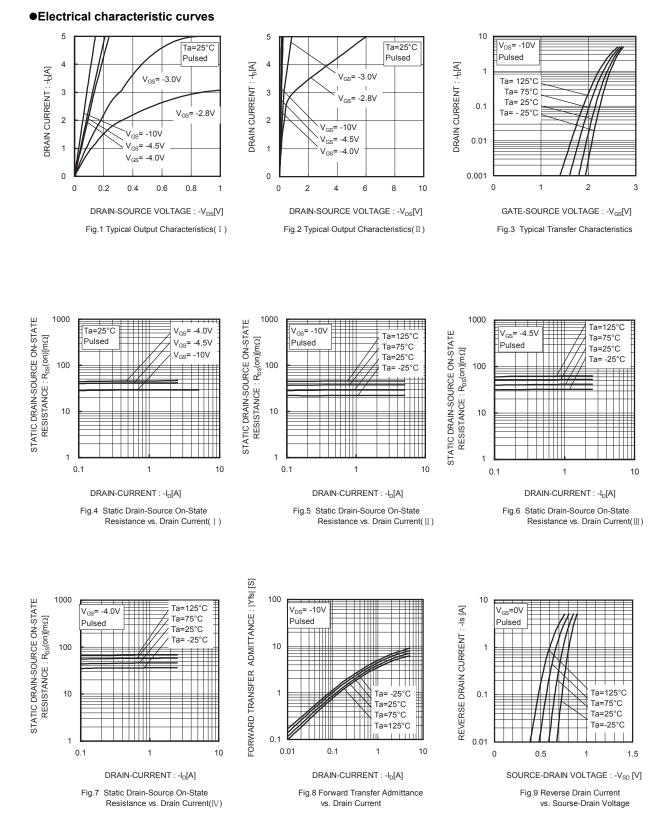
<It is the same ratings for Tr1 and Tr2.>

| Forward voltage V_{SD}^* 1.2 V I_s =-5A, V_{GS} =0 | Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|--|-----------------|--------------|------|------|------|------|--|
| | Forward voltage | V_{SD}^{*} | - | - | -17 | V | I _s =–5A, V _{GS} =0V |

*Pulsed

Data Sheet

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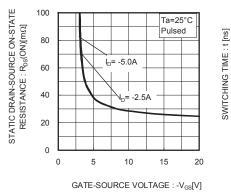
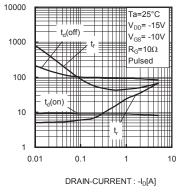
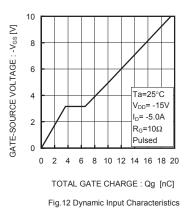
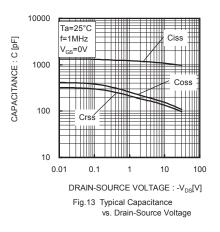


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage









Measurement circuits

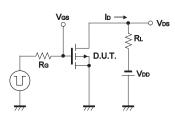


Fig.1-1 Switching Time Measurement Circuit

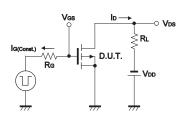


Fig.2-1 Gate Charge Measurement Circuit

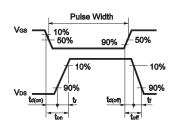


Fig.1-2 Switching Waveforms

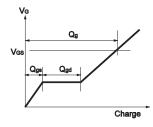


Fig.2-2 Gate Charge Waveform

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